# Application Report

# INA240-SEP Production Flow and Reliability Report



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### 1 Trademarks

All trademarks are the property of their respective owners.



# 2 Texas Instruments Enhanced Product Qualification and Reliability Report

TI qualification testing is a risk mitigation process that is engineered to assure device longevity in customer applications. Wafer fabrication process and package level reliability are evaluated in a variety of ways that may include accelerated environmental test conditions with subsequent derating to actual use conditions. Manufacturability of the device is evaluated to verify a robust assembly flow and assure continuity of supply to customers, TI Enhanced Products are qualified with industry standard test methodologies performed to the intent of Joint Electron Devices Engineering Council (JEDEC) standards and procedures. Texas Instruments Enhanced Products are certified to meet GEIA-STD-0002-1 Aerospace Qualified Electronic Components.



# 3 Space Enhanced Plastic Production Flow

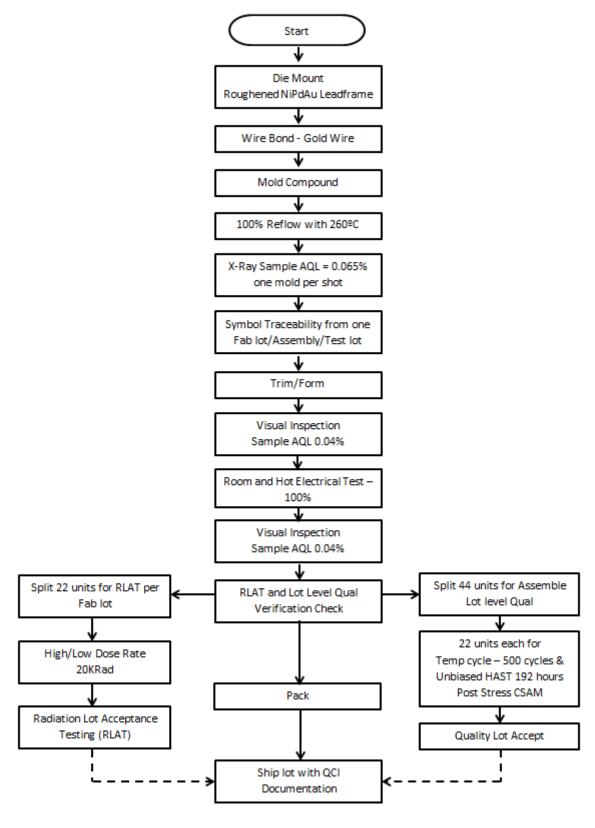


Figure 3-1. Space Enhanced Plastic Production Flow



# 4 Qualification by Similarity (Qualification Family)

A new device can be qualified either by performing full scale quality and reliability test on the actual device or using previously qualified device(s) through "Qualification by Similarity" (QBS) rules. By establishing similarity between the new device and those qualified previously, repetitive test will be eliminated, allowing for timely production release. When adopting QBS methodology, the emphasis is on qualifying the differences between a previously qualified product and the new product under consideration. The QBS rules for a technology, product, test parameter or package shall define which attributes are required to remain fixed in order for the QBS rules to apply. The attributes which are expected and allowed to vary will be reviewed and a QBS plan shall be developed, based on the reliability impact assessment above, specifying what subset of the full complement of environmental stresses is required to evaluate the reliability impact of those variations. Each new device shall be reviewed for the conformance to the QBS rule sets applicable to the device. See JEDEC JESD47 for more information.

Table 4-1. Device Baseline

TI Device:	INA240PMPWTPSEP/ INA240PMPWPSEP		Assembly Site:	TI-MLA (Malaysia)	
DLA VID:	V62/18615		Test Site:	TI-MLA (Malaysia)	
Wafer Fab:	MAINEFAB		Pin/Package Type:	TSSOP (PW)   8	
Fab Process:	ABCD6		Leadframe:	Cu	
Fab Technology:	BICMOS		Termination Finish:	NiPdAu	
Die Revision:			Bond Wire:	24.3 μm Au	
Die Name:	GHINA240A1ACPH		Moisture Sensitivity:	MSL 3/ 260°C	
ESD CDM:	±1000V				
ESD HBM:	±2000V				
1Baseline information in effect as of the date of this report					

**Table 4-2. Space Enhanced Products New Device Qualification Matrix** 

Note that qualification by similarity ("qualification family") per JEDEC JESD47 is allowed				
Description	Condition	Sample Size Used/ Rejects	Lots Required	Test Method
Electromigration	Maximum Recommended Operating Conditions	N/A	N/A	Per TI Design Rules
Wire Bond Life	Maximum Recommended Operating Conditions	N/A	N/A	Per TI Design Rules
Electrical Characterization	TI Data Sheet	10	3	N/A
Electrostatic Discharge	НВМ	3 units/voltage	1	EIA/JESD22-A114
Sensitivity	CDM			EIA/JESD22-C101
Latch-up	Per Technology	6/0	1	EIA/JESD78
Physical Dimensions	TI Data Sheet	5/0	1	EIA/JESD22- B100
Thermal Impedance	Theta-JA on board	Per Pin-Package	N/A	EIA/JESD51
Bias Life Test	125°C / 1000 hours or equivalent	77/0	3	JESD22-A108*
Biased HAST	130°C / 85% / 96 hours	77/0	3	JESD22-A110*
Extended Biased HAST	130°C / 85% / 250 hours (for reference)	77/0	1	JESD22-A110*
Unbiased HAST	130°C / 85% / 96 hours	77/0	3	JESD22-A.118*
Temperature Cycle	-65°C to +150°C non- biased for 500 cycles	77/0	3	JESD22-A104*
Solder Heat	260°C for 10 seconds	22/0	1	JESD22-B106
Resistance to Solvents	Ink symbol only	12/0	1	JESD22-B107
Solderability	Condition A (steam age for 8 hours)	22/0	1	ANSI/J-STD-002-92
Flammability	Method A / Method B	5/0	1	UL-1964



### Table 4-2. Space Enhanced Products New Device Qualification Matrix (continued)

Note that qualification by similarity ("qualification family") per JEDEC JESD47 is allowed					
Condition	Sample Size Used/ Rejects	Lots Required	Test Method		
Per wire size	5 units x 30/0 bonds	3	JESD22-B116		
Per wire size	5 units x 30/0 bonds	3	ASTM F-459		
Per die size	5/0	3	TM 2019		
150 °C / 1,000 hours	15/0	3	JESD22-A103-A*		
Surface Mount Only	12	1	J-STD-020-A*		
Total Ionization Dose, and Single-Event Latchup	5 units/dose level	1	MIL-STD-883/Method 1019		
TML (Total Mass Lost), CVCM (Collected Volatile Condensable material), WVR (Water vapor recorded)	5	1	ASTM E595		
	Per wire size Per wire size Per die size Per die size 150 °C / 1,000 hours Surface Mount Only Total Ionization Dose, and Single-Event Latchup TML (Total Mass Lost), CVCM (Collected Volatile Condensable material), WVR (Water vapor	Condition  Sample Size Used/ Rejects  Per wire size 5 units x 30/0 bonds  Per wire size 5 units x 30/0 bonds  Per die size 5/0  150 °C / 1,000 hours 15/0  Surface Mount Only 12  Total Ionization Dose, and Single-Event Latchup  TML (Total Mass Lost), CVCM (Collected Volatile Condensable material), WVR (Water vapor	Condition     Sample Size Used/ Rejects     Lots Required       Per wire size     5 units x 30/0 bonds     3       Per wire size     5 units x 30/0 bonds     3       Per die size     5/0     3       150 °C / 1,000 hours     15/0     3       Surface Mount Only     12     1       Total Ionization Dose, and Single-Event Latchup     5 units/dose level     1       TML (Total Mass Lost), CVCM (Collected Volatile Condensable material), WVR (Water vapor     5     1		

Outgas Test Report www.ti.com

# **5 Outgas Test Report**

Outgassing test was performed on 5 units. A total mass loss (TML) of 1.00% and collected volatile condensable material (CVCM) of 0.10% were used as screening levels for rejection of spacecraft materials. The outgas test was performed in a vacuum environment of less than  $5 \times 10$  –5 torr according to ASTM E 595, for a duration of 24 hours, at 125°C. The TML, CVCM, and the amount of Water Vapor Recovered (WVR) were measured after the test.

**Table 5-1. Outgas Test Results** 

SAMPLE	TML	CVCM	WVR
	(%)	(%)	(%)
INA240	0.07	<0.01	0.06

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#### Quality and Reliability Data Disclaimer

The attached quality and reliability information is specific to the TI Enhanced Plastic product family of plastic encapsulated commercial-off-the-shelf (COTS) semiconductor products and components. Due to possible differences in product assembly and test baselines, this information is NOT APPLICABLE to TI standard, industrial, or automotive catalog commercial products.

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